Discrete POWER & Signal **Technologies**

PN3565



PN3565



NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA. Sourced from Process 10. See PN100 for characteristics.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CEO}	Collector-Emitter Voltage	25	V
V _{CBO}	Collector-Base Voltage	30	V
V_{EBO}	Emitter-Base Voltage	6.0	V
Ic	Collector Current - Continuous 500		mA
T _J , T _{stg}	Operating and Storage Junction Temperature Range -55 to +150		°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

Thermal Characteristics TA = 25°C unless otherwise noted				
Symbol	Characteristic	Max	Units	
		PN3565		
P _D	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{\theta_{JC}}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction to Ambient	200	°C/W	

NPN General Purpose Amplifier (continued)

Electrical Characteristics TA = 25°C unless otherwise noted						
Symbol	Parameter	Test Conditions	Min	Max	Units	
OFF CHARACTERISTICS						
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage*	$I_{\rm C} = 2.0 {\rm mA}, I_{\rm B} = 0$	25		V	
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	30		V	
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 10 \ \mu A, I_{C} = 0$	6.0		V	
I _{CBO}	Collector Cutoff Current	$V_{CB} = 25 \text{ V}, I_E = 0$		50	nA	
h _{FE} V _{CE(sat)}	ACTERISTICS* DC Current Gain Collector-Emitter Saturation Voltage	$V_{CE} = 10 \text{ V}, \text{ I}_{C} = 1.0 \text{ mA}$ $I_{C} = 1.0 \text{ mA}, \text{ I}_{B} = 0.1 \text{ mA}$	150	600 0.35	V	
Cob	Output Capacitance	$V_{CB} = 5.0 V$		4.0	pF	
h _{ie}	Input Impedance	$I_{\rm C} = 1.0 \text{ mA}, V_{\rm CE} = 5.0 \text{ V},$ f = 1.0 kHz	2.0	20	kΩ	
h _{oe}	Output Admittance	$I_{C} = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 1.0 kHz	0.5	35	μmhos	
h _{fe}	Small-Signal Current Gain	$I_{c} = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 20 MHz $I_{c} = 1.0 \text{ mA}, V_{CE} = 5.0 \text{ V},$ f = 1.0 kHz	2.0	12 750		
			120	750		

*Pulse Test: Pulse Width $\leq 300~\mu\text{s},$ Duty Cycle $\leq 2.0\%$



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